NSN 5962-01-048-2015

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View Online at https://aerobasegroup.com/nsn/5962-01-048-2015
Body Length:
Between 1.230 inches and 1.285 inches
Body Width:
Between 0.510 inches and 0.545 inches
Body Height:
Between 0.150 inches and 0.225 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-40.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
Features Provided:
Hermetically sealed and programmable and w/buffered output and positive outputs and burn in
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
P-type metal oxide-semiconductor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-20.0 volts power source and 0.5 volts power source
Time Rating Per Chacteristic:
900.00 nanoseconds propagation delay time, low to high level output and 900.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
86360-515c9506-02 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a

Yes - demil/mli

Unit Of Measure:

Demilitarization:

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